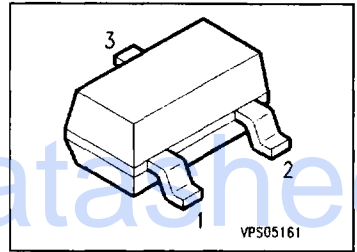


## PNP Silicon AF Transistors

**BCW 67**  
**BCW 68**

- For general AF applications
- High current gain
- Low collector-emitter saturation voltage
- Complementary types: BCW 65, BCW 66 (NPN)



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| Type     | Marking | Ordering Code<br>(tape and reel) | Pin Configuration |   |   | Package <sup>1)</sup> |
|----------|---------|----------------------------------|-------------------|---|---|-----------------------|
|          |         |                                  | 1                 | 2 | 3 |                       |
| BCW 67 A | DAs     | Q62702-C1560                     | B                 | E | C | SOT-23                |
| BCW 67 B | DBs     | Q62702-C1480                     |                   |   |   |                       |
| BCW 67 C | DCs     | Q62702-C1681                     |                   |   |   |                       |
| BCW 68 F | DFs     | Q62702-C1893                     |                   |   |   |                       |
| BCW 68 G | DGs     | Q62702-C1322                     |                   |   |   |                       |
| BCW 68 H | DHs     | Q62702-C1555                     |                   |   |   |                       |

<sup>1)</sup> For detailed information see chapter Package Outlines.

## Maximum Ratings

| Parameter                                     | Symbol    | Values         |        | Unit |
|---|-----------|----------------|--------|------|
|   |           | BCW 67         | BCW 68 |      |
| Collector-emitter voltage                     | $V_{CE0}$ | 32             | 45     | V    |
| Collector-base voltage                        | $V_{CB0}$ | 45             | 60     |      |
| Emitter-base voltage                          | $V_{EB0}$ | 5              | 5      |      |
| Collector current                             | $I_C$     | 800            |        | mA   |
| Peak collector current                        | $I_{CM}$  | 1              |        | A    |
| Base current                                  | $I_B$     | 100            |        | mA   |
| Peak base current                             | $I_{BM}$  | 200            |        |      |
| Total power dissipation, $T_S = 79\text{ °C}$ | $P_{Tot}$ | 330            |        | mW   |
| Junction temperature                          | $T_j$     | 150            |        | °C   |
| Storage temperature range                     | $T_{sig}$ | - 65 ... + 150 |        |      |

## Thermal Resistance

|                                  |             |       |     |
|----------------------------------|-------------|-------|-----|
| Junction - ambient <sup>1)</sup> | $R_{th JA}$ | ≤ 285 | K/W |
| Junction - soldering point       | $R_{th JS}$ | ≤ 215 |     |

<sup>1)</sup> Package mounted on epoxy pcb 40 mm × 40 mm × 1.5 mm/6 cm<sup>2</sup> Cu.

## Electrical Characteristics

at  $T_A = 25^\circ\text{C}$ , unless otherwise specified.

| Parameter   | Symbol        | Values |      |      | Unit          |
|---|---------------|--------|------|------|---------------|
|   |               | min.   | typ. | max. |               |
| <b>DC characteristics</b>                                   |               |        |      |      |               |
| Collector-emitter breakdown voltage<br>$I_C = 10\text{ mA}$ | $V_{(BR)CEO}$ |        |      |      | V             |
| BCW 67  |               | 32     | —    | —    |               |
| BCW 68  |               | 45     | —    | —    |               |
| Collector-base breakdown voltage<br>$I_C = 10\ \mu\text{A}$ | $V_{(BR)CBO}$ |        |      |      |               |
| BCW 67  |               | 45     | —    | —    |               |
| BCW 68  |               | 60     | —    | —    |               |
| Emitter-base breakdown voltage, $I_E = 10\ \mu\text{A}$     | $V_{(BR)EBO}$ | 5      | —    | —    |               |
| Collector cutoff current<br>$V_{CB} = 32\text{ V}$          | $I_{CBO}$     |        |      |      | nA            |
| BCW 67  |               | —      | —    | 20   | nA            |
| $V_{CB} = 45\text{ V}$                                      |               |        |      |      | nA            |
| BCW 68  |               | —      | —    | 20   | nA            |
| $V_{CB} = 32\text{ V}, T_A = 150^\circ\text{C}$             |               |        |      |      | $\mu\text{A}$ |
| BCW 67  |               | —      | —    | 20   | $\mu\text{A}$ |
| $V_{CB} = 45\text{ V}, T_A = 150^\circ\text{C}$             |               |        |      |      | $\mu\text{A}$ |
| BCW 68  |               | —      | —    | 20   | $\mu\text{A}$ |
| Emitter-base cutoff current, $V_{EB} = 4\text{ V}$          | $I_{EBO}$     | —      | —    | 20   | nA            |
| DC current gain <sup>1)</sup>                               | $h_{FE}$      |        |      |      | —             |
| $I_C = 100\ \mu\text{A}, V_{CE} = 10\text{ V}$              |               |        |      |      |               |
| BCW 67 A, BCW 68 F  |               | 35     | —    | —    |               |
| BCW 67 B, BCW 68 G  |               | 50     | —    | —    |               |
| BCW 67 C, BCW 68 H  |               | 80     | —    | —    |               |
| $I_C = 10\text{ mA}, V_{CE} = 1\text{ V}$                   |               |        |      |      |               |
| BCW 67 A, BCW 68 F  |               | 75     | —    | —    |               |
| BCW 67 B, BCW 68 G  |               | 120    | —    | —    |               |
| BCW 67 C, BCW 68 H  |               | 180    | —    | —    |               |
| $I_C = 100\text{ mA}, V_{CE} = 1\text{ V}$                  |               |        |      |      |               |
| BCW 67 A, BCW 68 F  |               | 100    | 160  | 250  |               |
| BCW 67 B, BCW 68 G  |               | 160    | 250  | 400  |               |
| BCW 67 C, BCW 68 H  |               | 250    | 350  | 630  |               |
| $I_C = 500\text{ mA}, V_{CE} = 2\text{ V}$                  |               |        |      |      |               |
| BCW 67 A, BCW 68 F  |               | 35     | —    | —    |               |
| BCW 67 B, BCW 68 G  |               | 60     | —    | —    |               |
| BCW 67 C, BCW 68 H  |               | 100    | —    | —    |               |

<sup>1)</sup> Pulse test:  $t \leq 300\ \mu\text{s}, D = 2\%$ .

## Electrical Characteristics

at  $T_A = 25\text{ }^\circ\text{C}$ , unless otherwise specified.

| Parameter | Symbol | Values |      |      | Unit |
|-----------|--------|--------|------|------|------|
|           |        | min.   | typ. | max. |      |

### DC characteristics

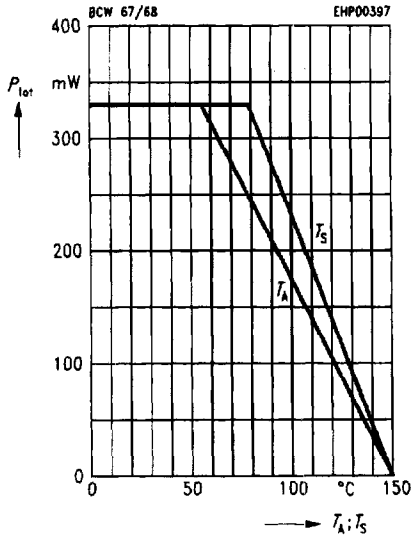
|  |             |   |   |            |   |
|--|-------------|---|---|------------|---|
| Collector-emitter saturation voltage <sup>1)</sup><br>$I_C = 100\text{ mA}$ , $I_B = 10\text{ mA}$<br>$I_C = 500\text{ mA}$ , $I_B = 50\text{ mA}$ | $V_{CEsat}$ | – | – | 0.3<br>0.7 | V |
| Base-emitter saturation voltage <sup>1)</sup><br>$I_C = 100\text{ mA}$ , $I_B = 10\text{ mA}$<br>$I_C = 500\text{ mA}$ , $I_B = 50\text{ mA}$      | $V_{BEsat}$ | – | – | 1.25<br>2  |   |

### AC characteristics

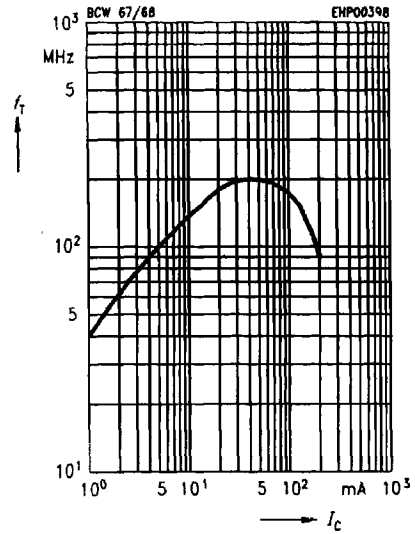
|  |           |   |     |   |     |
|--|-----------|---|-----|---|-----|
| Transition frequency<br>$I_C = 50\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $f = 20\text{ MHz}$ | $f$       | – | 200 | – | MHz |
| Output capacitance<br>$V_{CB} = 10\text{ V}$ , $f = 1\text{ MHz}$                          | $C_{obo}$ | – | 6   | – | pF  |
| Input capacitance<br>$V_{EB} = 0.5\text{ V}$ , $f = 1\text{ MHz}$                          | $C_{ibo}$ | – | 60  | – |     |

<sup>1)</sup> Pulse test:  $t \leq 300\text{ }\mu\text{s}$ ,  $D = 2\%$ .

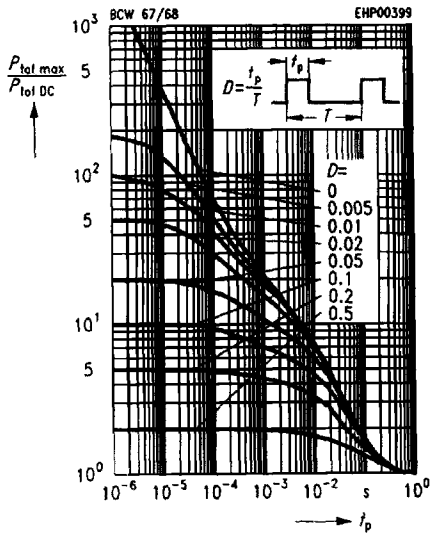
**Total power dissipation**  $P_{tot} = f(T_A^*; T_S)$   
 \* Package mounted on epoxy



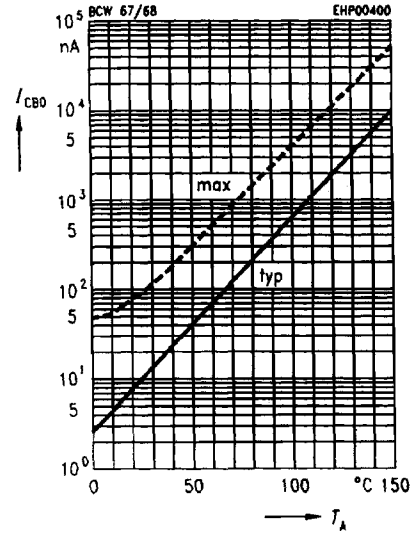
**Transition frequency**  $f_T = f(I_C)$   
 $V_{CE} = 5 V$



**Permissible pulse load**  $P_{tot max}/P_{tot DC} = f(t_p)$



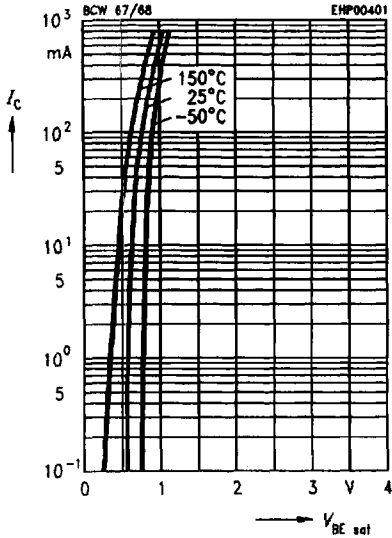
**Collector cutoff current**  $I_{CB0} = f(T_A)$   
 $V_{CB} = V_{CEmax}$



**Base-emitter saturation voltage**

$I_C = f(V_{BE sat})$

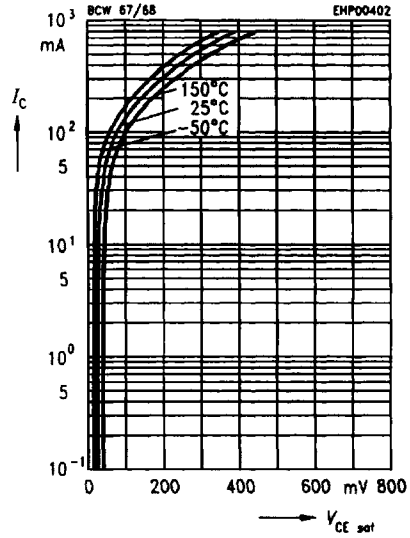
$h_{FE} = 10$



**Collector-emitter saturation voltage**

$I_C = f(V_{CE sat})$

$h_{FE} = 10$



**DC current gain  $h_{FE} = f(I_C)$**

$V_{CE} = 1 V$

